

**Prof. Dr. sc. nat. H. Jörg Osten**

- 04/2007 - 03/2009 Dean of the Faculty of Electrical Engineering and Computer Science  
since 03/2002 Professor for Electronic Materials and Semiconductor Technology at the  
Leibniz University of Hannover  
Member of the Executive Board of the Laboratory for Nano and Quantum  
Engineering
- 2000 - 2002 Project leader *Alternative Gate Dielectrics*
- 1999 - 2002 Department head *Breakthrough*
- 1998 - 2000 Project leader *HBT Transfer to Motorola*
- 1997 - 1999 Project leader *SiGe:C HBT Module*
- 1990 - 2002 IHP GmbH Frankfurt(Oder)  
Molecular beam epitaxy and material development for Si-based electronics  
(i.e. *C in Si and SiGe for MOS and HBT's*)
- 1988 - 1990 Institute for Semiconductor Physics (IHP) in Frankfurt (Oder)
- 09/1987 Professor for Physical Chemistry at the Academy of Sciences
- 1986 Habilitation (*isotope effects on nuclear properties*)
- 04-07/1985 Postdoc at the Theoretical Chemistry Department, Cambridge University/GB
- 10/1983 - 09/1984 Postdoc at the Department of Chemistry  
University of Illinois at Chicago/USA
- 05-08/1983 Postdoc in Sofia (Bulgaria)
- 1983 PhD in Physical Chemistry  
(*noise decoupling in nuclear magnetic resonance*)
- 1980 - 1988 Central Institute for Physical Chemistry Berlin
- 1975 - 1980 University of Wroclaw and Poznan/Poland  
Physics Diploma 1980
- 1957 born in Hennigsdorf (State of Brandenburg)
- Publications ~280 papers in refereed journals (h-index: 36)  
5 books  
~30 patents  
~85 invited talks  
~200 contributed talks at international conferences  
Committee member at various international conferences